

#### **Description**

The HI5121 usesadvancedtrenchtechnologytoprovide excellent  $R_{DS(ON)}$ , low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch or in PWM applications.



#### **General Features**

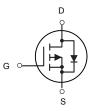
 $V_{DS} = -20V, I_{D} = -3A$ 

 $R_{DS(ON)}$  < 130m  $\Omega$  @  $V_{GS}$ =-4.5V

 $R_{DS(ON)}$  < 148m  $\Omega$  @  $V_{GS}$ =-2.5V

# **Application**

PWM applications Load switch



P-Channel MOSFET

#### **Package Marking and Ordering Information**

Product ID	Pack	Marking	Qty(PCS)
HI5121	SOT-23	A19T	3000

#### Absolute Maximum Ratings (TA=25 ℃ unless otherwise noted)

Symbol	nbol Parameter		Unit	
VDS	Drain-Source Voltage	-20	V	
Vgs	Gate-Source Voltage	±12	V	
I <sub>D</sub>	Drain Current-Continuous	-3	А	
Ірм	Drain Current-Pulsed (Note 1)	-10	А	
P <sub>D</sub>	Maximum Power Dissipation	0.7	W	
T <sub>J</sub> ,T <sub>STG</sub>	Operating Junction and Storage Temperature Range -55 To 150		°C	
Rеја	Thermal Resistance,Junction-to-Ambient (Note 2)	178	°C/W	



## Electrical Characteristics (T<sub>J</sub>=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Тур	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> =-250μA	-20			V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-15V,V <sub>GS</sub> =0V,T <sub>C</sub> =25°C			-1	μΑ
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ = $\pm 10V$ , $V_{DS}$ = $0V$			±100	nA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}$ = $V_{GS}$ , $I_D$ =-250 $\mu$ A	-0.4	-0.62	-1.0	V
		V <sub>GS</sub> = -4.5V, I <sub>D</sub> =-2A		100	130	
Static Drain-Source On-Resistance	$R_{DS(ON)}$	V <sub>GS</sub> = -2.5V, I <sub>D</sub> =-1.6A		132	148	mΩ
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-2A,V <sub>GS</sub> =0V		-0.8	-1.2	V
Maximum Body-Diode Continuous Current	I <sub>S</sub>				-2.3	А
Dynamic Parameters						
Input Capacitance	C <sub>iss</sub>			260		pF
Output Capacitance	$C_{oss}$	$V_{DS}$ =-10V, $V_{GS}$ =0V,f=1MHZ		44		
Reverse Transfer Capacitance	C <sub>rss</sub>			29		
Switching Parameters						
Total Gate Charge	$Q_g$			3.9		
Gate Source Charge	$Q_{gs}$	$V_{GS}$ =-4.5 $V$ , $V_{DS}$ =-10 $V$ , $I_D$ =-2 $A$		0.7		nC
Gate Drain Charge	$Q_{gd}$			0.9		
Turn-on Delay Time	$t_{D(on)}$			12		
Turn-on Rise Time	t <sub>r</sub>	$V_{GS}$ =-4.5V, $V_{DD}$ =-10V, $I_{D}$ =-1A,		54		
Turn-off Delay Time	$t_{D(off)}$	$R_{GEN}=2.5\Omega$		15		ns
Turn-off Fall Time	t <sub>f</sub>			9		

<sup>A. Pulse Test: Pulse Width≤300us,Duty cycle ≤2%.
B. Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch.</sup> 



### **Typical Performance Characteristics**

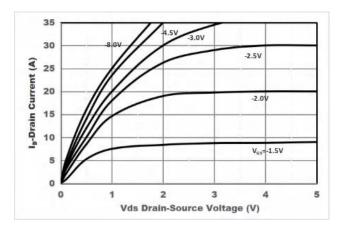


Figure 1. Output Characteristics

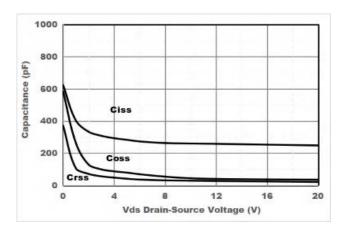


Figure 3. Capacitance Characteristics

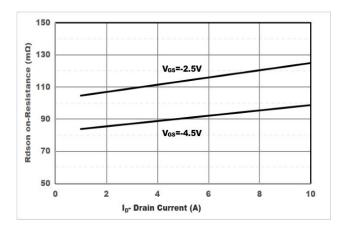


Figure 5. Drain-Source on Resistance

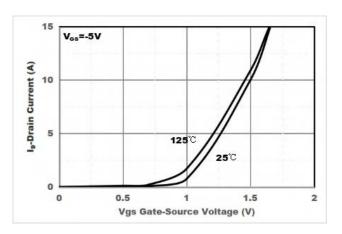


Figure 2. Transfer Characteristics

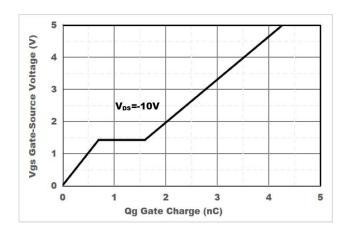


Figure 4. Gate Charge

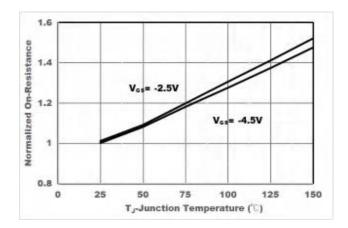
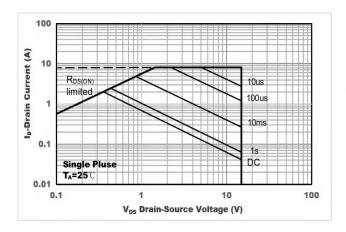


Figure 6. Drain-Source on Resistance





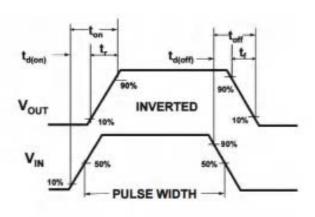
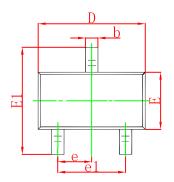
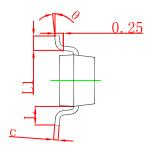


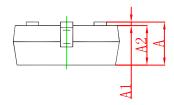
Figure8. Switching wave



# **SOT-23 Package Outline Dimensions**

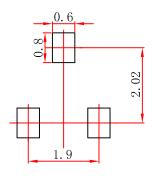






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
Α	0.900	1.150	0.035	0.045	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.050	0.035	0.041	
b	0.300	0.500	0.012	0.020	
С	0.080	0.150	0.003	0.006	
D	2.800	3.000	0.110	0.118	
Е	1.200	1.400	0.047	0.055	
E1	2.250	2.550	0.089	0.100	
е	0.950	TYP	0.037 TYP		
e1	1.800	2.000	0.071	0.079	
L	0.550	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020	
θ	0°	8°	0°	8°	

# **SOT-23 Suggested Pad Layout**



- Note: 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
  3.The pad layout is for reference purposes only.



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